

GMN08504LM

GOOD-ARK Electronics

N-Channel 40V (D-S) Power MOSFET

Features

- 100% Avalanche Tested
- Extremely Low Losses with Low FOM Rdson*Qg
- Halogen Free, Pb-Free
- RoHS Compliant



PDFN5060

4 G 0-

D 5, 6, 7, 8

S 1, 2, 3

Applications

- DC-DC
- Motors, lamps
- Power switching

Absolute Maximum Rating	gs (Tյ=25°C unless oth	erwise noted)		
Parameter	Symbol Value Uni		Unit	
Drain Source Voltage	n Source Voltage V _{DS} 40		V	
Gate Source Voltage	V _{GS}	±20	V	
Drain Current, Continuous V _{GS} =10V <i>(Note 1)</i>	T _c =25°C	ID	68	А
Drain Current, Pulsed (Note 2)		I _{DM}	125	А
Single Avalanche Energy @ L=0.1mH	E _{AS}	31	mJ	
Power Dissipation (Note 3)	T _C =25°C	PD	1.67	W
Operating Junction/ Storage Temperat	TJ/ TSTG	-55 to +150	°C	

Note 1: Calculated continuous current based on maximum allowable junction temperature. Note 2: Repetitive rating; pulse width limited by max. junction temperature.

Thermal Characteristics			
Parameter	Symbol	Мах	Unit
Thermal Resistance Junction to Case (Note 3)	R _{thJC}	30	°C/W
Thermal Resistance Junction to Ambient (Note 4)	R _{thJA}	85	°C/W

Note 3: The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance. Note 4: The value of R_{BJA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with TA =25 °C.

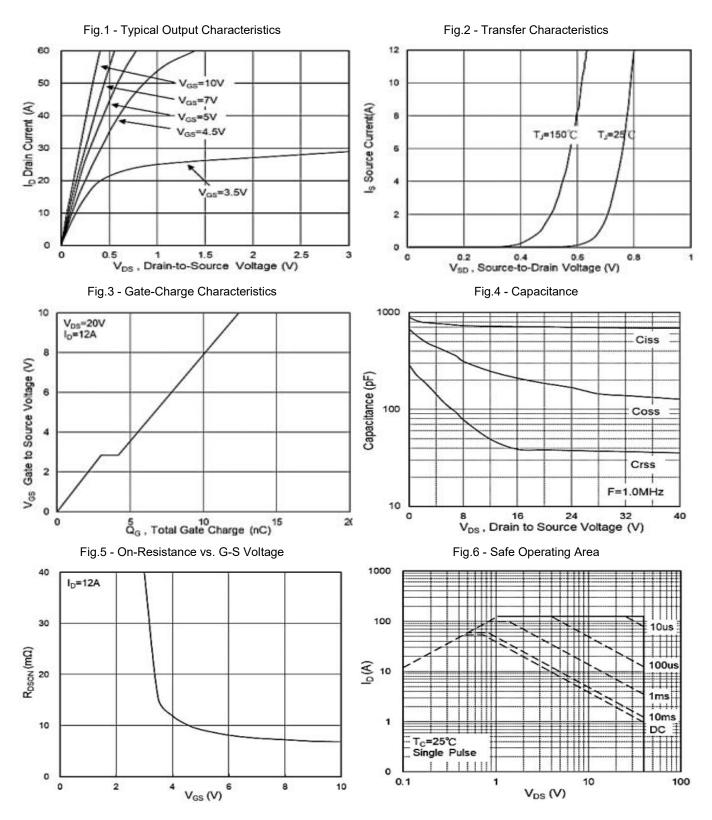


Electrical Characteristics (T _J =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250µA	40			V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =32V, V _{GS} =0V			1.0	uA
Gate Threshold Voltage	V _{GS(TH)}	V_{DS} = V_{GS} , I_{DS} =250uA	1.2		2.5	V
Gate Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			±100	nA
Drain-Source On-state	_	V _{GS} =10V, I _D =12A		6.9	8.5	mΩ
Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =10A		10.5	15	
Total Gate Charge	Qg			5.8		nC
Gate-Source Charge	Q _{gs}	$I_D = 12A,$ $V_{DS}=20V,$		3		
Gate-Drain Charge	Q _{gd}	V _{GS} = 4.5V		1.2		
Turn-on Delay Time	t _{d(on)}			14.3		
Turn-on Rise Time	tr	V _{GS} =10V, V _{DD} =15V,		5.6		
Turn-off Delay Time	t _{d(off)}	I _D =1A, R _G =3.3Ω		20		ns
Turn-off Fall Time	t _f			11		
Input Capacitance	C _{iss}			690		
Output Capacitance	Coss	$V_{GS=0}V, V_{DS}=15V, f=1MHz$		193		pF
Reverse Transfer Capacitance	C _{rss}			38		

Reverse Diode Characte	erse Diode Characteristics (TJ = 25°C unless otherwise noted)					
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Forward Current, Continuous	I _{SD}	T _c =25°C			30	А
Diode Forward Voltage	V _{SD}	I _F =1A, V _{GS} =0V			1	V



Typical Characteristics Curves (T_J = 25°C unless otherwise noted)





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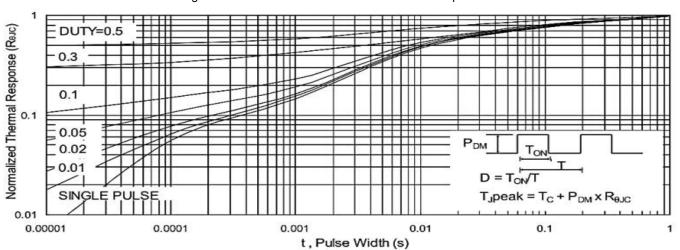
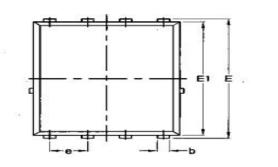


Fig.7 - Normalized Maximum Transient Thermal Impedance

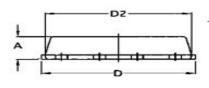


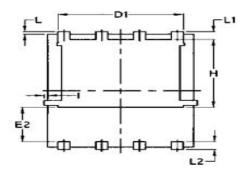
Package Outline Dimensions (Unit: millimeters)

PDFN5060





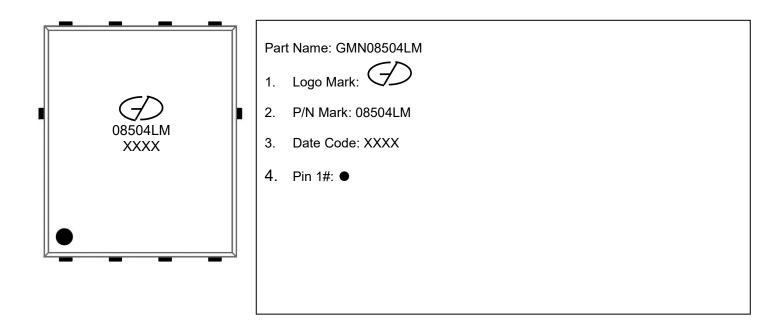




Symbol	Common				
	m	ım	Inch		
	Mim	Max	Min	Max	
A	1.03	1.17	0.0406	0.0461	
b	0.34	0.48	0.0134	0.0189	
С	0.824	0.0970	0.0324	0.082	
D	4.80	5.40	0.1890	0.2126	
D1	4.11	4.31	0.1618	0.1697	
D2	4.80	5.00	0.1890	0.1969	
E	5.95	6.15	0.2343	0.2421	
E1	5.65	5.85	0.2224	0.2303	
E2	1.60	/	0.0630	/	
е	1.27 BSC		0.05	BSC	
L	0.05	0.25	0.0020	0.0098	
L1	0.38	0.50	0.0150	0.0197	
L2	0.38	0.50	0.0150	0.0197	
Н	3.30	3.50	0.1299	0.1378	
I	/	0.18	/	0.0070	



Marking Outline





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